

TOSHIBA BI-DIRECTIONAL TRIODE THYRISTOR SILICON PLANAR TYPE

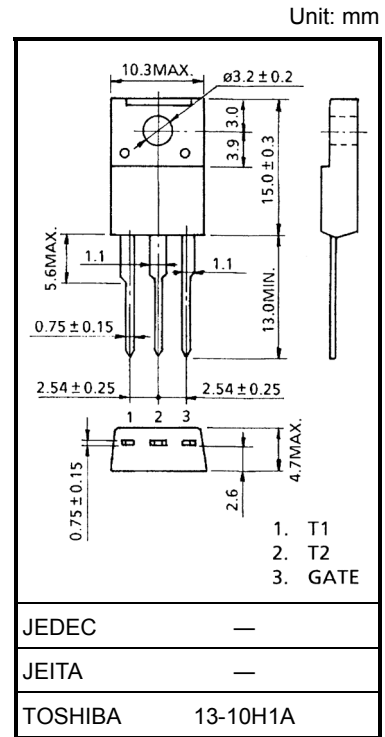
SM2GZ47, SM2GZ47A, SM2JZ47, SM2JZ47A

AC POWER CONTROL APPLICATIONS

- I_T (RMS) = 1A ($T_a = 65^\circ\text{C}$ without radiator)
- Gate Trigger Current: $I_{GT} = 5\text{mA Max. (TYPE "A")}$
- Repetitive Peak Off-State Voltage: $V_{DRM} = 400\text{V, } 600\text{V}$
- R.M.S On-State Current: I_T (RMS) = 2A ($T_c = 110^\circ\text{C}$)
- Isolation Voltage: $V_{ISOL} = 1500\text{V (AC, } t = 60\text{s)}$

ABSOLUTE MAXIMUM RATINGS

CHARACTERISTIC	SYMBOL	RATING	UNIT
Repetitive Peak Off-State Voltage and Repetitive Peak Reverse Voltage	SM2GZ47 SM2GZ47A	400	V
	SM2JZ47 SM2JZ47A	600	
R.M.S On-State Current (Full Sine Waveform)	$T_c = 110^\circ\text{C}$	2	A
	$T_a = 65^\circ\text{C}$	1	
Peak One Cycle Surge On-State Current (Non-Repetitive)	I_{TSM}	8 (50Hz)	A
		8.8 (60Hz)	
I2t Limit Value	I2t	0.32	A2s
Peak Gate Power Dissipation	P_{GM}	3	W
Average Gate Power Dissipation	P_G (AV)	0.3	W
Peak Gate Voltage	V_{FGM}	10	V
Peak Gate Current	I_{GM}	1.6	A
Junction Temperature	T_j	-40~125	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	-40~125	$^\circ\text{C}$
Isolation Voltage (AC, $t = 1\text{min.}$)	V_{ISOL}	1500	V

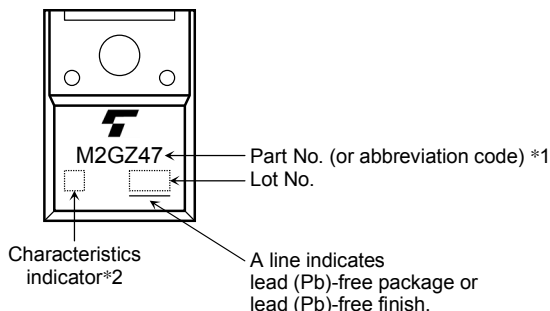


Weight: 1.7 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

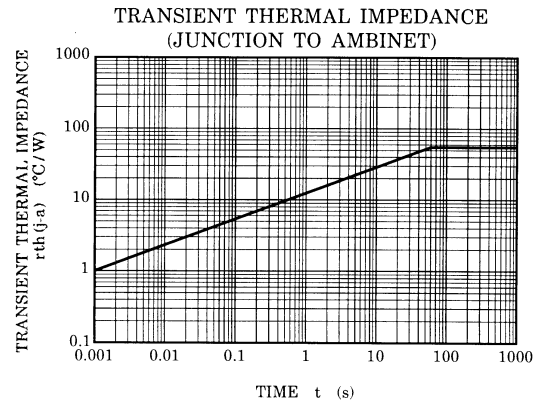
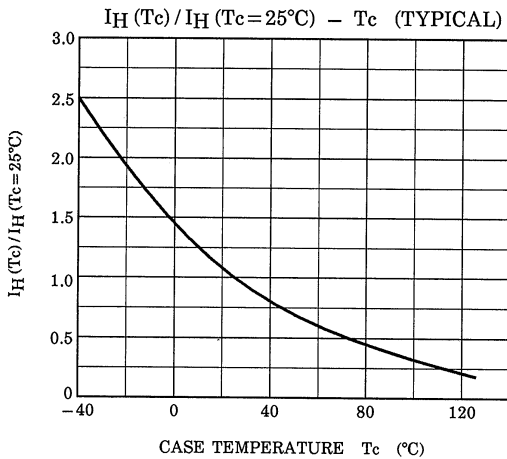
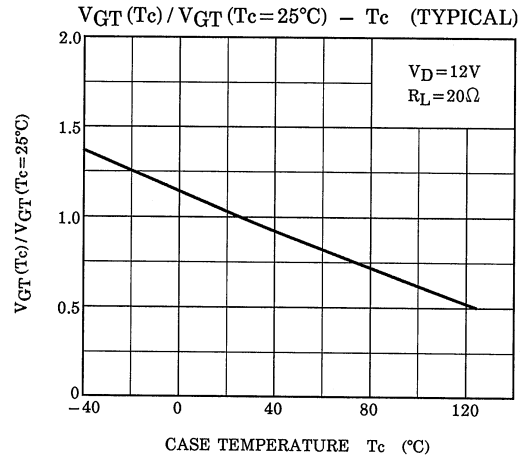
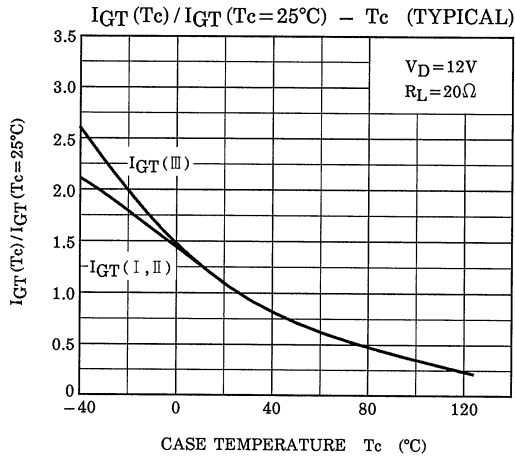
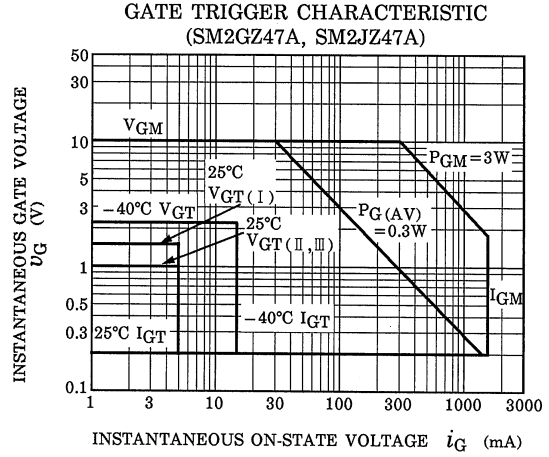
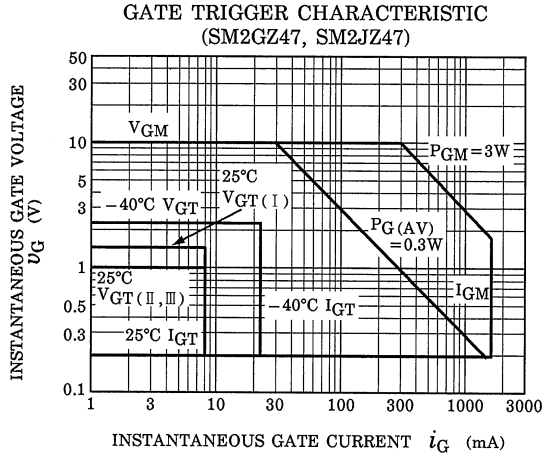
MARKING

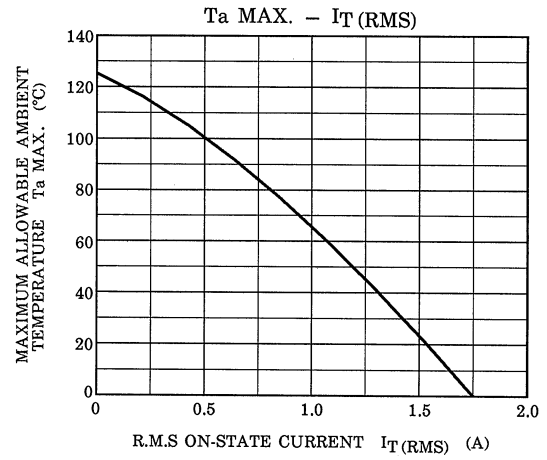
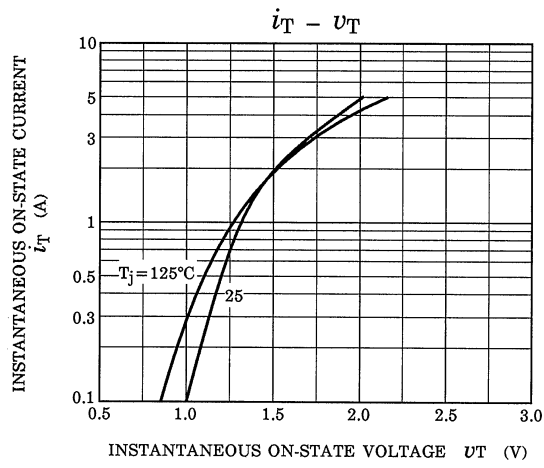


	Part No. (or abbreviation code)	Part No.
*1	M2GZ47	SM2GZ47, SM2GZ47A
	M2JZ47	SM2JZ47, SM2JZ47A
*2	Nothing	SM2GZ47, SM2JZ47
	A	SM2GZ47A, SM2JZ47A

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT		
Repetitive Peak Off-State Current		I_{DRM}	$V_{DRM} = \text{Rated}$	—	—	20	μA		
Gate Trigger Voltage	I	V_{GT}	$V_D = 12\text{V}$ $R_L = 20\Omega$	T2 (+), Gate (+)	—	—	1.5	V	
	II			T2 (+), Gate (-)	—	—	1		
	III			T2 (-), Gate (-)	—	—	1		
	IV			T2 (-), Gate (+)	—	—	—		
Gate Trigger Current	SM2GZ47 SM2JZ47	I_{GT}	$V_D = 12\text{V}$ $R_L = 20\Omega$	T2 (+), Gate (+)	—	—	8	mA	
				II	T2 (+), Gate (-)	—	—		8
				III	T2 (-), Gate (-)	—	—		8
				IV	T2 (-), Gate (+)	—	—		—
	SM2GZ47A SM2JZ47A			I	T2 (+), Gate (+)	—	—		5
				II	T2 (+), Gate (-)	—	—		5
				III	T2 (-), Gate (-)	—	—		5
				IV	T2 (-), Gate (+)	—	—		—
Peak On-State Voltage		V_{TM}	$I_{TM} = 3\text{A}$	—	—	1.7	V		
Gate Non-Trigger Voltage		V_{GD}	$V_D = \text{Rated}, T_c = 125^\circ\text{C}$	0.2	—	—	V		
Holding Current		I_H	$R_L = 100\Omega$	—	—	10	mA		
Thermal Resistance		$R_{th(j-a)}$	Junction to Ambient, AC	—	—	55	$^\circ\text{C} / \text{W}$		





<CONDITION>

- ◆ NO HEAT SINK
- ◆ LEAD FORMING : LB182
- ◆ PRINT BOARD

$\left(\begin{array}{l} t=1.6\text{mm} \\ \text{SOLDER LAND : } 2\text{mm}\phi \end{array} \right)$

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